

Radiation Tolerance of AIDA2020v2 LGADs manufactured at IMB-CNM



38th RD50 workshop

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Outline

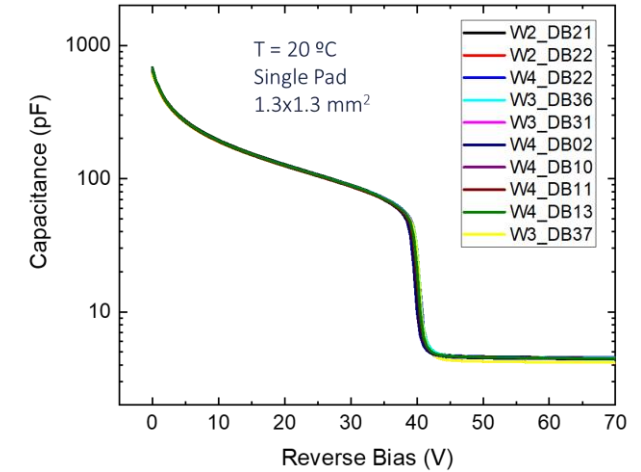


- Sample description
- Irradiation campaign: Fluence estimation.
- Charge collection vs fluence
- Short-time annealing.
- Timing vs fluence.
- Summary

AIDA 2020v2 technology (run # 12916)

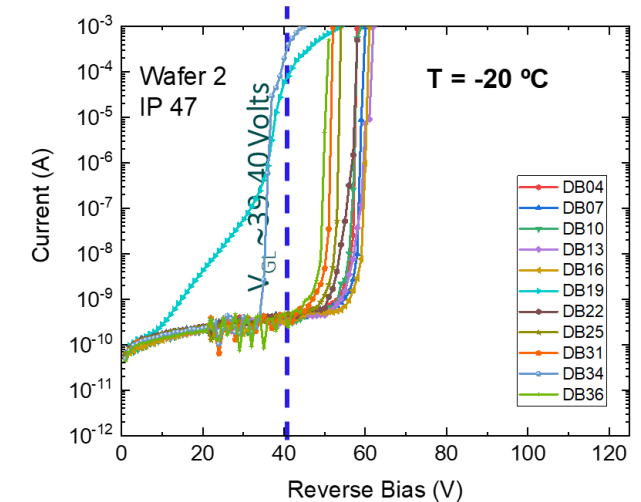
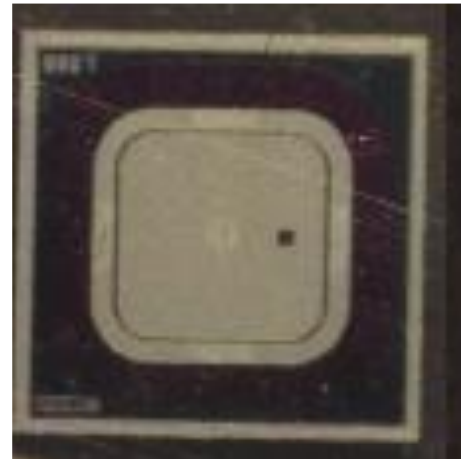
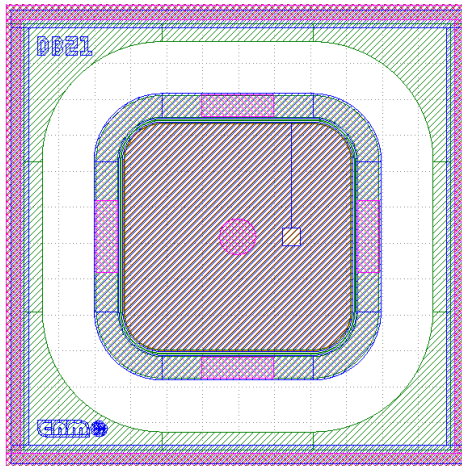


- **Four SiSi FZ wafers** with the same dose/energy parameters.
- Radiation tolerance study of total of 16 single-pads LGAD and 4 PIN diodes characterized.
- Single-pad layout accordingly to the designed pads of the ETL and HGTD sensors.



Wafer	Thickness (μm)	Dose (at/cm^2)	Energy (keV)
1-4	50	Medium	Low

Single-pad diodes

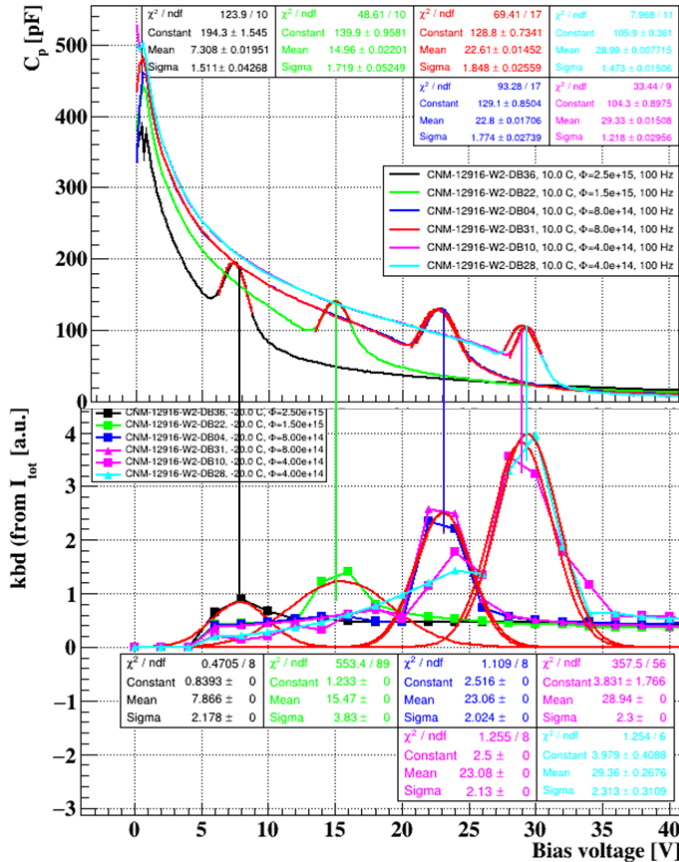


Irradiation campaign – Fluence dispersion



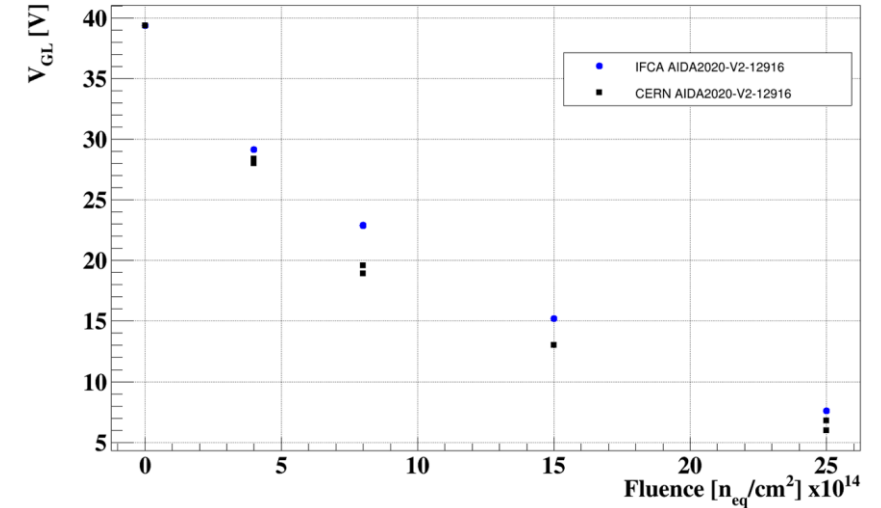
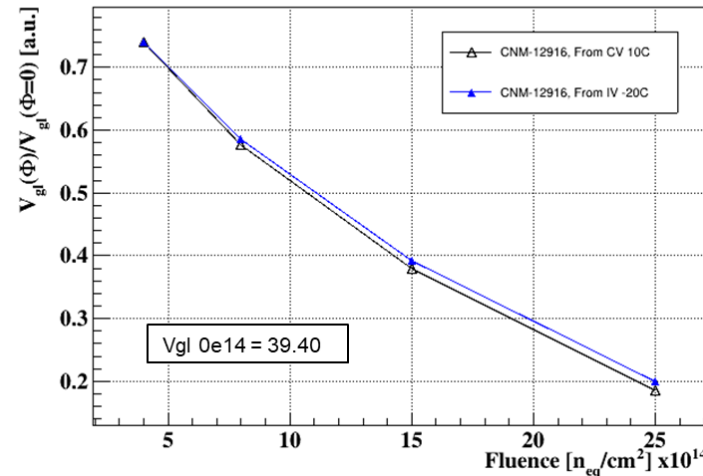
IFCA

- Neutron irradiated, four target fluences: $4e14$, $8e14$, $15e14$ & $25e14$ n_{eq}/cm^2
- Two irradiation batches @ Ljubljana: CERN (Summer 2020, **Annealed** 80 min at 60°) and IFCA (Fall 2020 **non-annealed**).



V_{GL} from CV			
$4E14 n_{eq}/cm^2$	$8E14 n_{eq}/cm^2$	$15E14 n_{eq}/cm^2$	$25E14 n_{eq}/cm^2$
29.16 V	22.70 V	14.96 V	7.3 V

V_{GL} from IV			
$4E14 n_{eq}/cm^2$	$8E14 n_{eq}/cm^2$	$15E14 n_{eq}/cm^2$	$25E14 n_{eq}/cm^2$
29.12 V	23.07 V	15.47 V	7.86 V

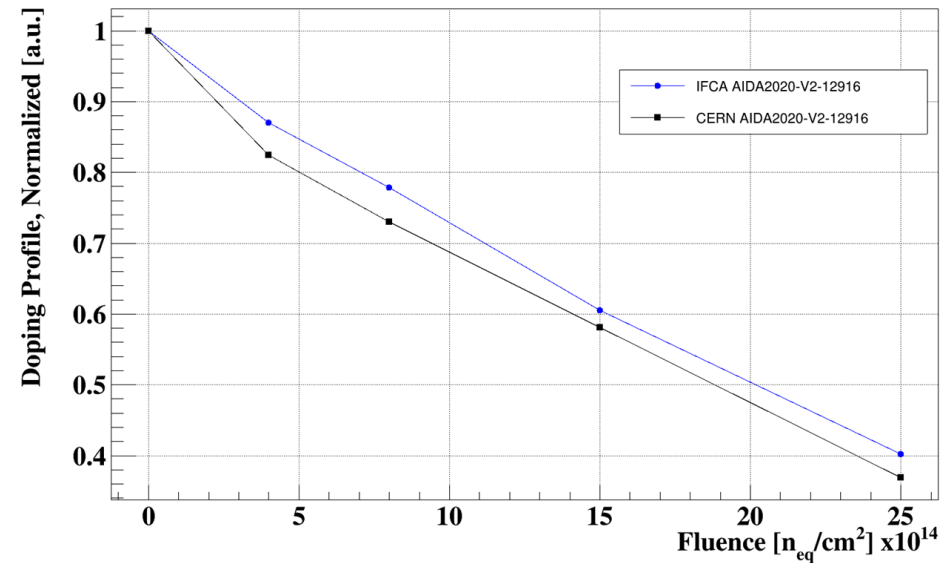
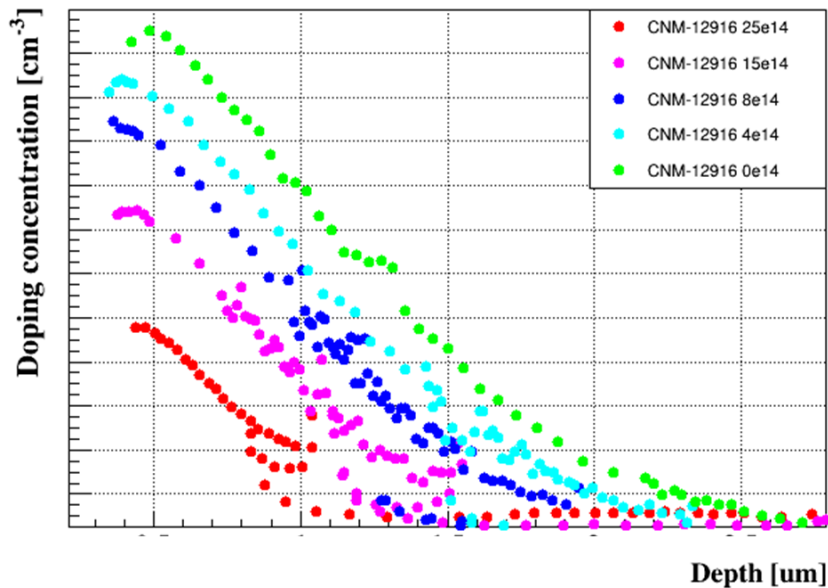


CERN samples possibly irradiated at higher fluences than IFCA samples ($V_{gl}@CERN > V_{gl}@IFCA$)

For kbd definition see M. Fernández RD50 37th

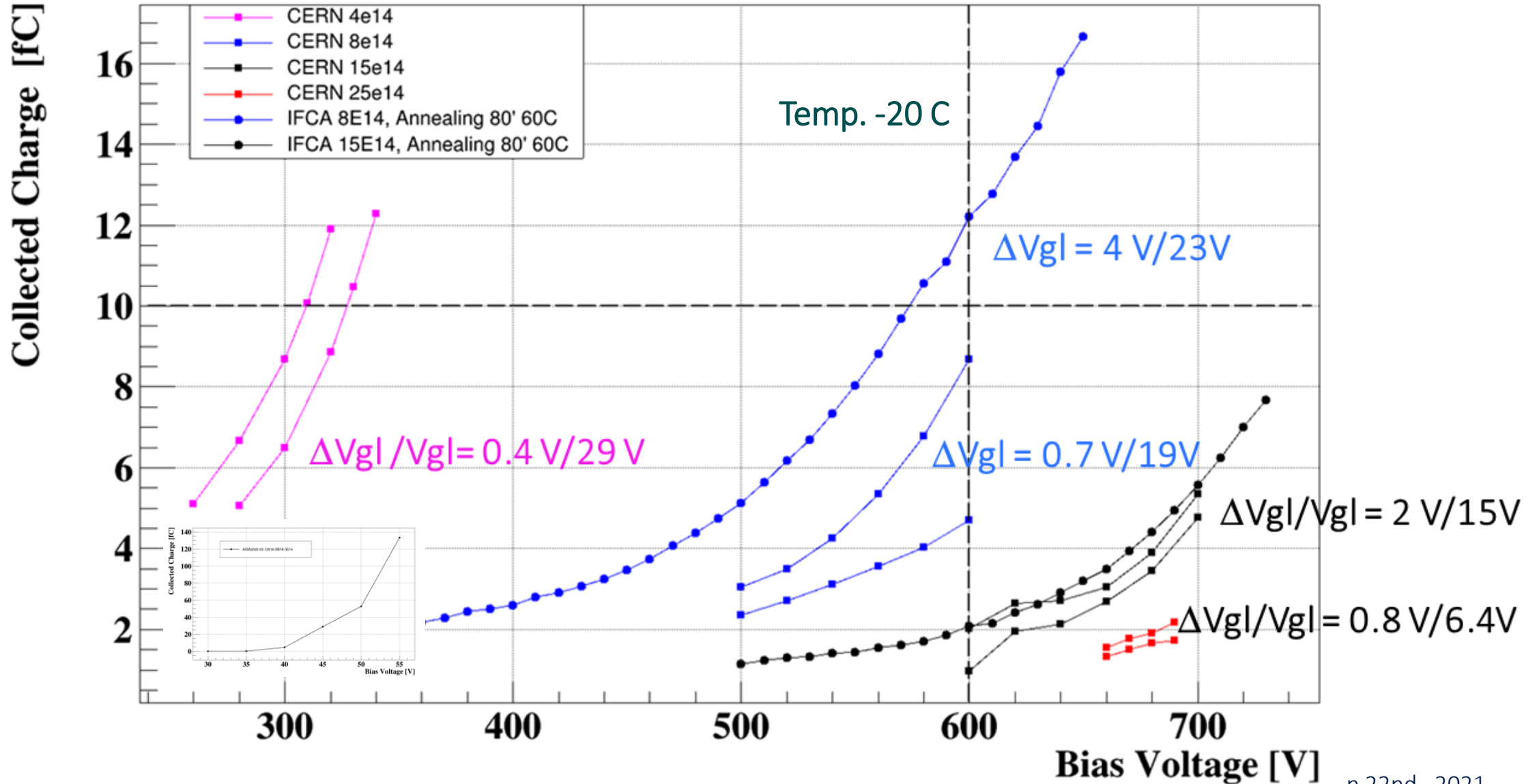
Irradiation campaign – Fluence dispersion (2)

- Neutron irradiated, four target fluences: $4e14$, $8e14$, $15e14$ & $25e14$ n_{eq}/cm^2
- Two irradiation batches: CERN (**Annealed** 80 min at 60°) and IFCA (**non-annealed**).



- The doping profiles confirm that the CERN samples were subjected to higher fluences (the effect of annealing will be shown later in the talk).

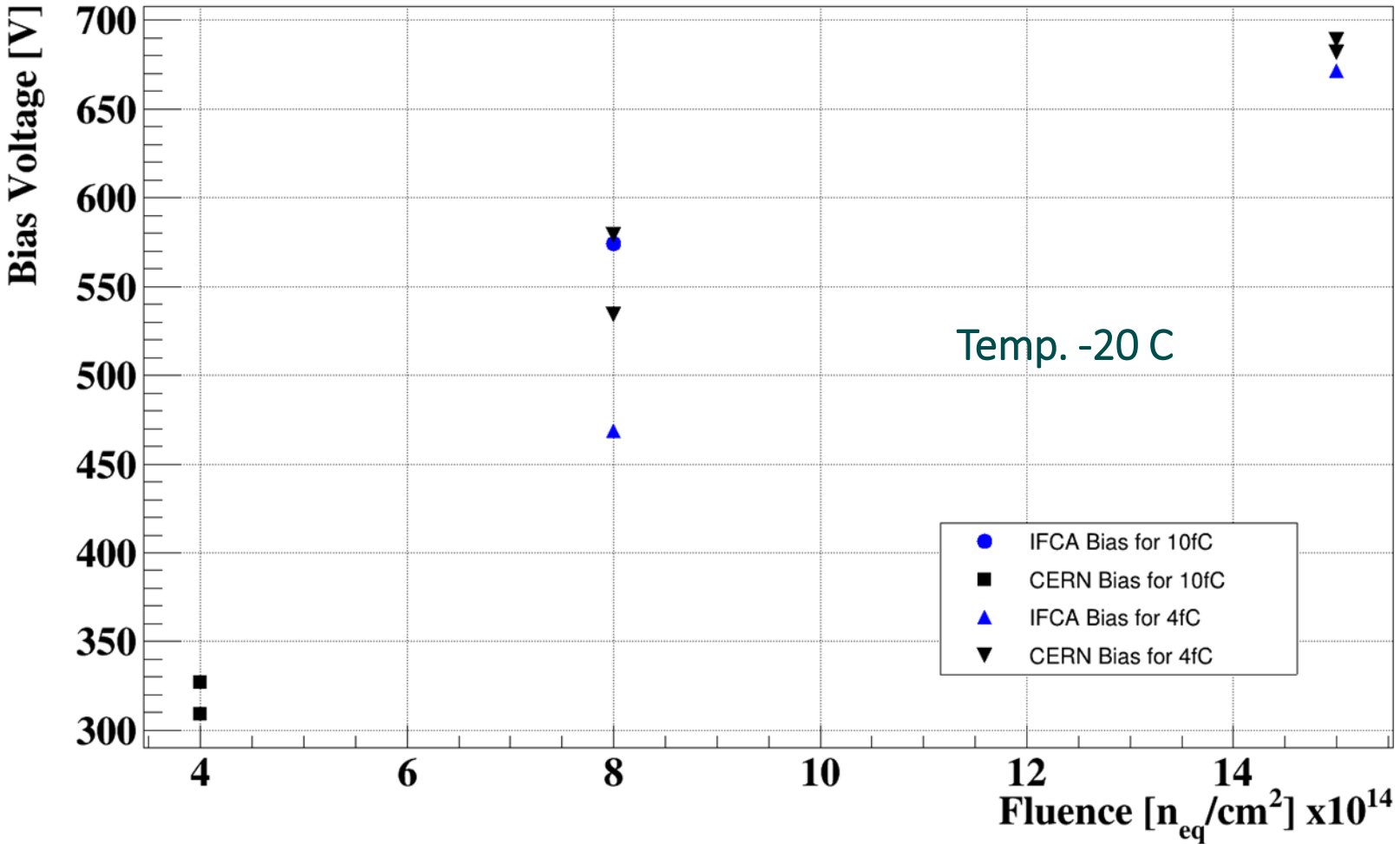
Charge collected vs Vbias



Collected charge: Operational voltage

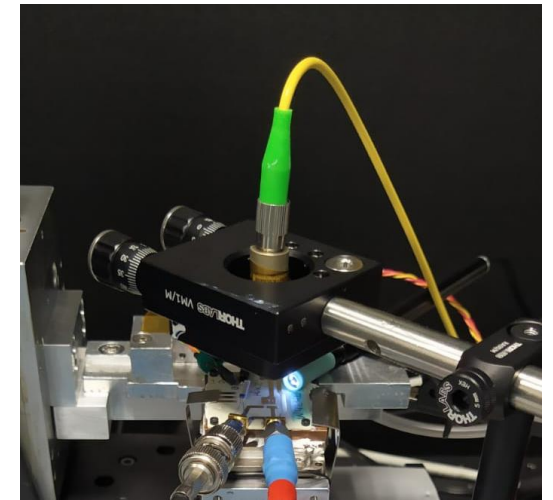
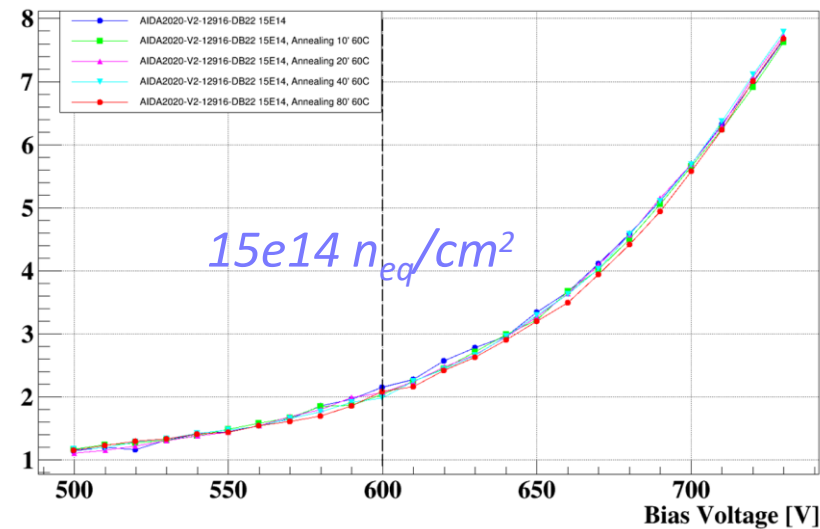
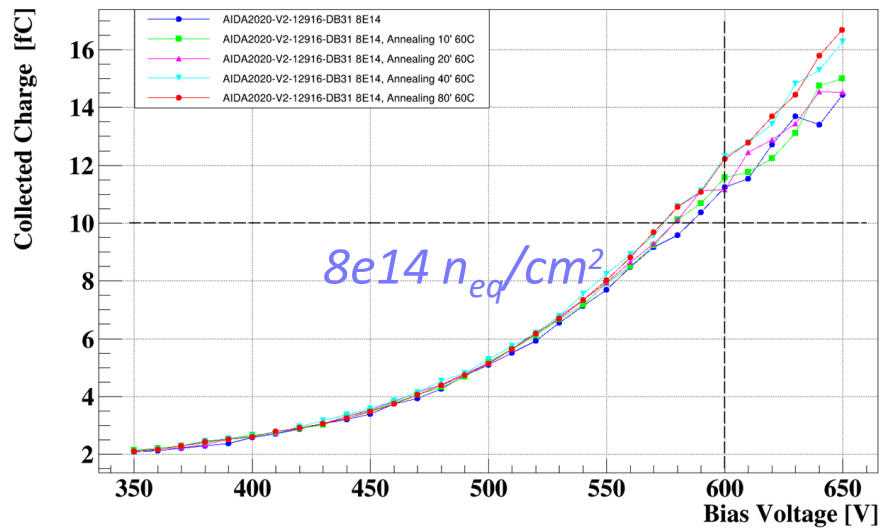


– What is the bias voltage needed for achieving 10fC/5fC?



Charge collected: Short-term annealing

- Motivation:
 - _ Is the observed scattering in charge collection due to lack of annealing?
- Short-term annealing of IFCA samples at 60°C: 10', 20', 40' and 80'.
- TCT IR laser setup

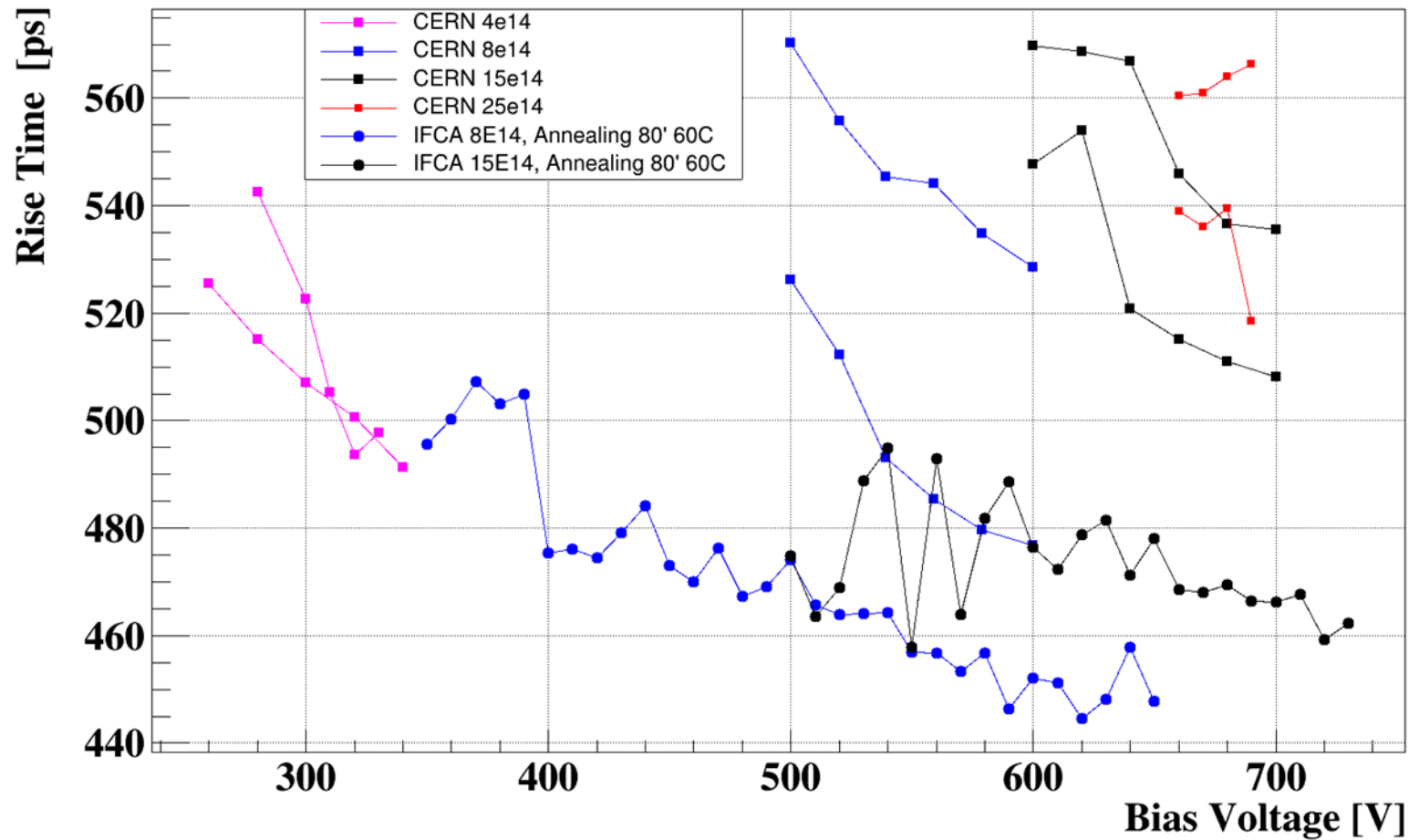


No significant effect observed

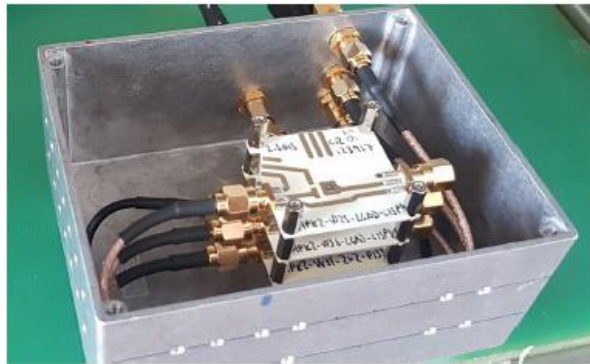
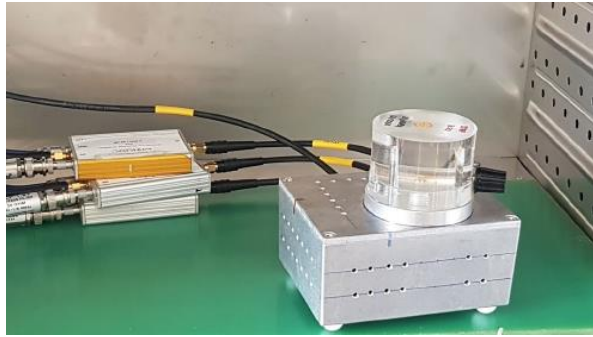
Timing vs fluence: Risetime



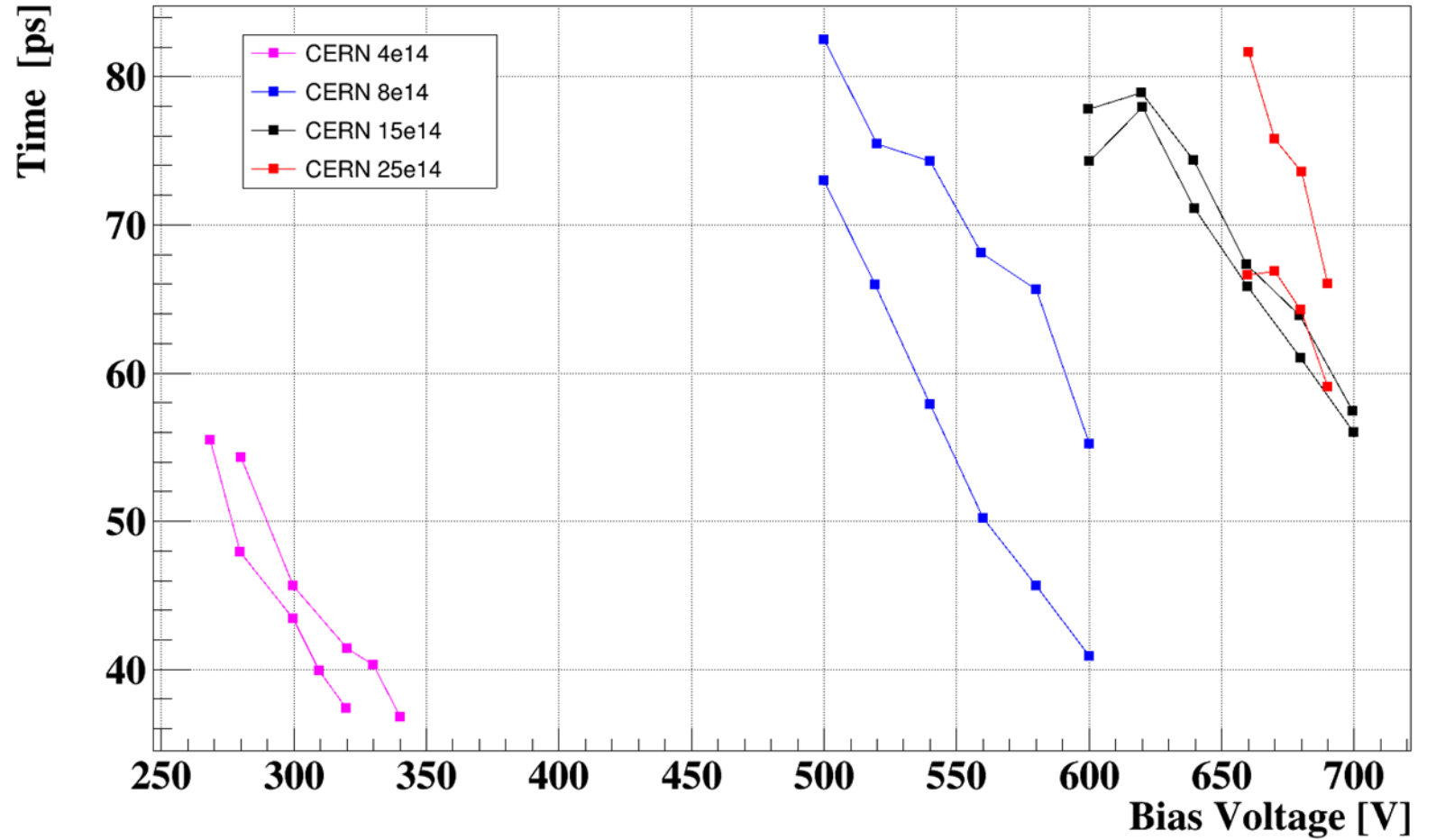
- All risetimes are well within the required range for fast timing



Timing vs fluence: time resolution



Timing estimation using a beta source
See E. Currás talk in this workshop
for details



Concluding remarks



- Full radiation tolerance study of the AIDA2020v2 LGAD production (the latest available production from IMB-CNM in FZ substrates)
- Radiation tolerance criteria ($Q > 10 \text{ fC}$, $V_{\text{bias}} < 12 \text{ V}/\mu\text{m}$) achieved up to approximately 10^{15} n/cm^2 fluence for neutrons
- However, a few *well-known* caveats apply^(*):
 - _ The radiation tolerance to protons has not been studied yet (acceptor removal depends on irradiation type)
 - _ Incertitude on the actual fluence introduces dispersion on results. For neutron-irradiated samples in the summer/fall 2020 irradiation campaigns a fluence cross-check based on V_{gl} and/or doping profiles advisable.
 - _ Timing performance are done using very fast, power hungry, bulky amplifiers; high bandwidth and high sampling rate digital scopes with algorithms using the full waveform information, bottom line: **expect an optimistic timing resolution estimate.**
- In addition, Non-irradiated AIDA2020v2 LGAD at -20 C has V_{op} close to V_{gl} .

* And are mostly valid for recent HPK-P2 and FKB productions

AIDA2020-V2-12916

